AMENDMENTS TO THE CLAIMS

The listing of claims will replace all prior versions, and listings, of claims in the application.

Listing of Claims

 (Currently Amended) A method of making a diamond product having a projection or a depression on a surface thereof by etching, said method comprising the steps of:

forming a diamond substrate with a mask layer including a metal layer in at least one part thereof; and

etching said diamond substrate formed with said mask layer with a plasma of a mixed gas composed of a gas containing an oxygen atom and a gas containing a fluorine atom;

wherein said fluorine atom has a concentration within the range of 0.04% to 6% with respect to the total number of atoms in said mixed gas, said plasma is produced by generating a high-frequency discharge between two plate electrodes, said high-frequency discharge is generated by supplying an electric power of less than 1.0 not less than 0.28 W/cm² between said plate electrodes, and said mixed gas further contains nitrogen gas, thereby to form the diamond product having the projection or depression with a side face with an angle of inclination of at least 78 degrees,

wherein said mixed gas contains nitrogen gas in an amount such that the intensity ratio A/B of said mixture is greater than the intensity ratio A/B of the mixed gas with no nitrogen, where A is the intensity of an emission peak caused by atomic oxygen and B is the intensity of an emission peak caused by molecular oxygen.

- 2. (Cancelled)
- (Previously Presented) A method of making a diamond product according to claim 1, wherein said gas containing said fluorine atom is CF₄ gas; and

wherein said CF_4 gas has a concentration within the range of 0.02% to 3% with respect to the total number of molecules in said mixed gas.

4. (Original) A method of making a diamond product according to claim 1, wherein said gas containing said oxygen atom is one of O₂, CO₂, and a mixed gas composed of O₂ and CO₂.

Claims 5-11. (Cancelled)

12. (Currently Amended) A method of making a diamond product by etching a diamond substrate, said method comprising the steps of:

etching said diamond substrate using a plasma of a mixed gas, wherein the plasma of the mixed gas comprises oxygen atoms, fluorine atoms, and nitrogen atoms;

generating a high-frequency discharge between two plate electrodes by supplying an electric power of less than 1.0 not less than 0.28 W/cm² between said plate electrodes; and wherein the mixed gas has a fluorine atom concentration within the range of 0.04% to 6% with respect to the total number of atoms in said mixed gas, and

wherein said mixed gas contains nitrogen gas in an amount such that the intensity ratio A/B of said mixture is greater than the intensity ratio A/B of the mixed gas with no nitrogen,

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where A is the intensity of an emission peak caused by atomic oxygen and B is the intensity of an emission peak caused by molecular oxygen.

- 13. (Cancelled)
- 14. (Previously Presented) The method of claim 12, wherein the diamond substrate has a mask, and wherein the diamond product has an angle of inclination of at least 78 degrees.
- 15. (Withdrawn) A diamond product having a projection or a depression on a surface thereof, the projection or depression having at least one side face with an angle of inclination of at least 78 degrees.
- 16. (Previously Presented) The method of claim 1, wherein the mixed gas contains an N_2 concentration that is not less than 2.5% and not more than 40%.
 - 17. (Cancelled)
 - 18. (Cancelled)
- 19. (New) The method of making a diamond product according to claim 1, wherein A is the intensity of an emission peak at a wavelength of 777 nm and B is the intensity of an emission peak at a wavelength of 558 nm.

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- 20. (New) The method of claim 12, wherein the mixed gas contains an N_2 concentration that is not less than 2.5% and not more than 40%.
- 21. (New) The method of making a diamond product according to claim 12, wherein A is the intensity of an emission peak at a wavelength of 777 nm and B is the intensity of an emission peak at a wavelength of 558 nm.
- 22. (New) The method of making a diamond product according to claim 1, wherein the electric power supplied between said plate electrodes is not more than 0.45 W/cm².
- 23. (New) The method of making a diamond product according to claim 12, wherein the electric power supplied between said plate electrodes is not more than 0.45 W/cm².